

AMENDMENT TO RULES COMMITTEE PRINT 119-

33

OFFERED BY MR. MOULTON OF MASSACHUSETTS

At the end of subtitle B of title II, insert the following new section:

1 **SEC. 2___ . PRODUCTION OF SPECIALTY SEMICONDUCTOR**
2 **DEVICES.**

3 (a) IN GENERAL.—Beginning on the date of enact-
4 ment of this section and ending five years after such date,
5 a covered federally funded research and development cen-
6 ter sponsored by the Department of Defense may—

7 (1) carry out research and development in part-
8 nership with a private entity relating to specialty
9 semiconductor devices; and

10 (2) in partnership with such private entity,
11 produce a limited number (as determined by the
12 Secretary of Defense) of specialty semiconductor de-
13 vices.

14 (b) CRITERIA.—For each specialty semiconductor de-
15 vice described in subsection (a), the covered federally
16 funded research and development center shall submit to
17 the Secretary of Defense a certification that includes the
18 following:

1 (1) There is a clear industry need for such de-
2 vice and no viable domestic laboratory or manufac-
3 turer to complete research and development, testing,
4 and certification of such device.

5 (2) A market survey conducted by the private
6 entity partner described in subsection (a)(1) has
7 demonstrated that there is no domestic industry in-
8 terest in production of such device.

9 (c) REPORT.—Not later than six months after the
10 date of the enactment of this section, and annually there-
11 after until the date that is five years after the date of
12 the enactment of this Act, the Secretary of Defense shall
13 submit to the congressional defense committees a report
14 on each use of the authority under subsection (a)(1) that
15 includes the following:

16 (1) A list of all new certifications granted pur-
17 suant to subsection (b) during the period covered by
18 the report with the name and description of the spe-
19 cialty semiconductor device certified for production.

20 (2) For each certification, a description of the
21 market survey conducted including responses from
22 manufacturers, and an explanation for why there is
23 no domestic industry interest in production.

1 (3) For each device produced or in production
2 under subsection (a) during the period covered by
3 the report, the—

4 (A) the name of the private entity partner
5 and the industry sector of such partner;

6 (B) order quantities received for each de-
7 vice; and

8 (C) the total number of each device pro-
9 duced.

10 (d) DEFINITIONS.—In this section:

11 (1) The term “covered federally funded re-
12 search and development center” means a federally
13 funded research and development center that, on the
14 date of the enactment of this section, is performing
15 one or more contracts with the Secretary of Defense.

16 (2) The term “specialty semiconductor device”
17 means an integrated circuit or discrete microelec-
18 tronic component designed for highly specific appli-
19 cations, but where no other domestic commercial en-
20 tity can produce these specialty semiconductor de-
21 vice.

